

TPC concentrator chip development: results & plans

E. Atkin for ASIC Lab of NRNU MEPHI

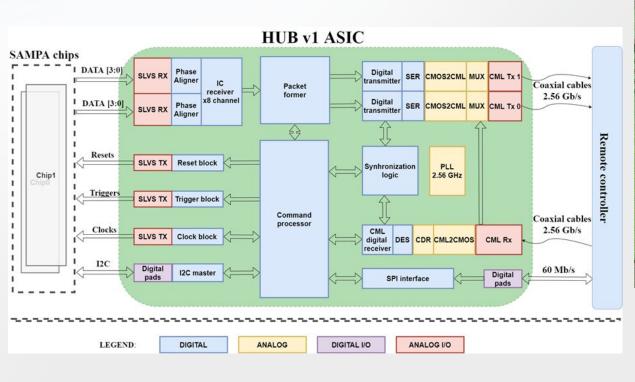
IX-th Collaboration Meeting of the MPD Experiment at the NICA Facility, JINR 27/04/2022

Outline

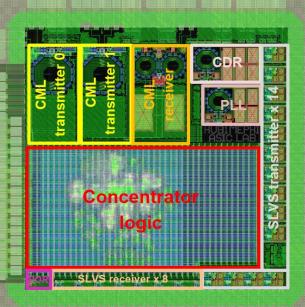
- Prototype ASIC Hub v1
- Test program, 2 PCBs
- Lab test board
- First results
- Demonstrator test bench
- Hub v2 ASIC plans

ASIC Hub v1: structure and specs

main functions: data concentration from two SAMPA chips and their transfer to counting room via fast 2.56 Gb/s bi-directional interface



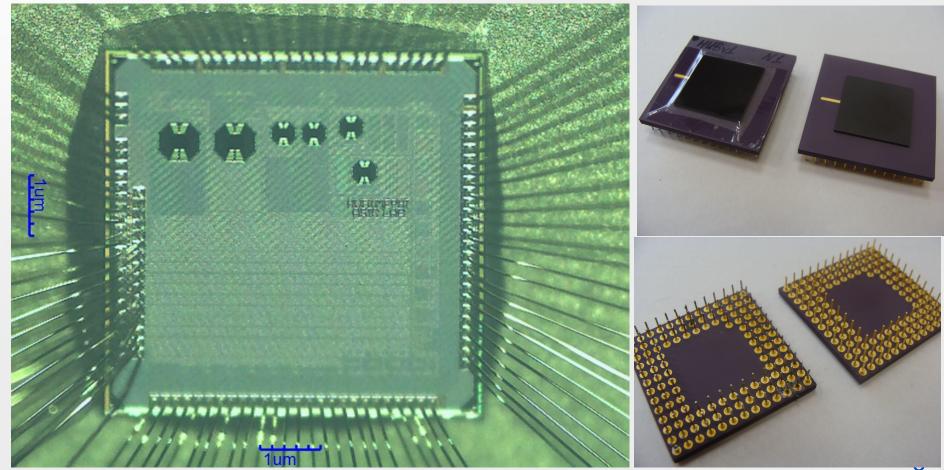
Specifications	Value
Technology	TSMC CMOS 65 nm
I/O voltage	2.5 V
Core voltage	1.2 V
Power consumption	< 500 mW



 Process – TSMC65 LP MS RF 1P9M_6X1Z1U_RDL;
 Chip area – 1980 x 1980 um;
 Bond pads – 111 (37 type CUP staggered & 74 type IN-LINE) Pad size – 57 x 69 um Pad Pitch – 60 um
 Technological run of Nov. 2020
 Readiness – July 2021
 types of packaging: CPGA 120 & caseless

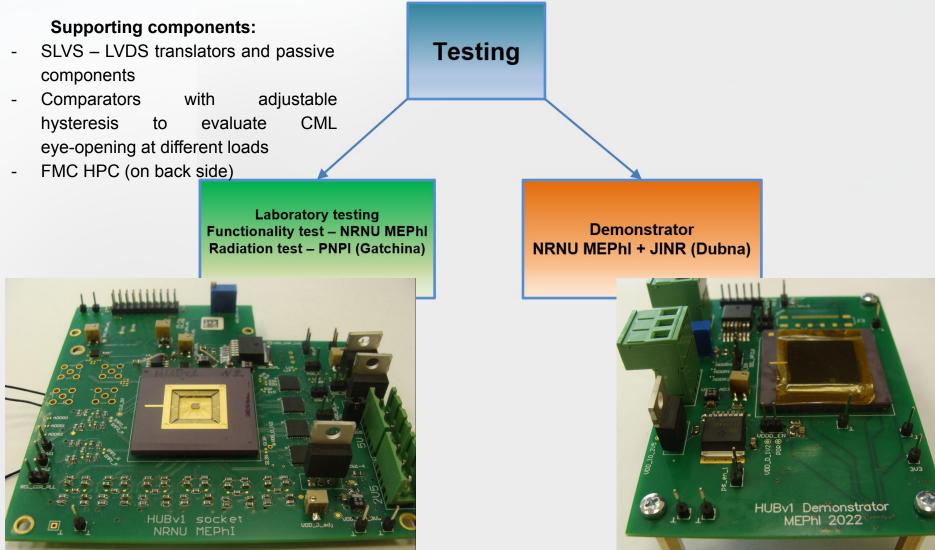
Hub v1 photos (chip & case)

Fabricated are 10 pcs in CPGA-120 package and 80 pcs - caseless



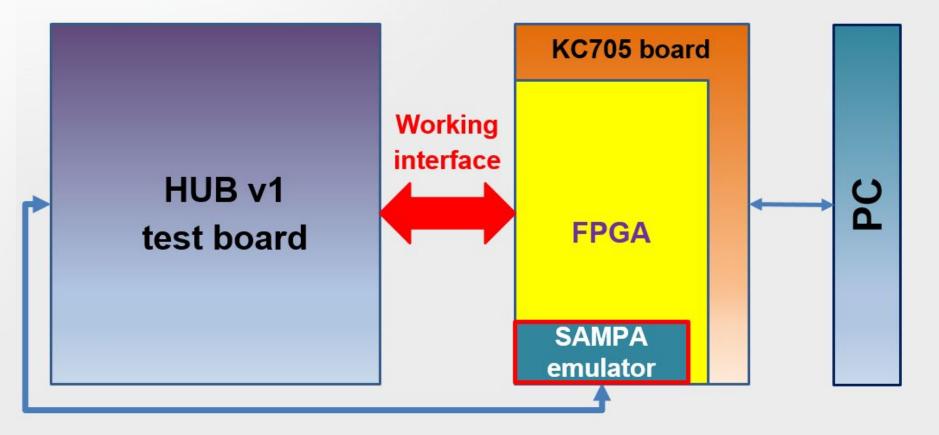
Test program (2 boards)

- 1) Laboratory phase (functionality & radiation tolerance)
- 2) Prototype demonstrator for TPC

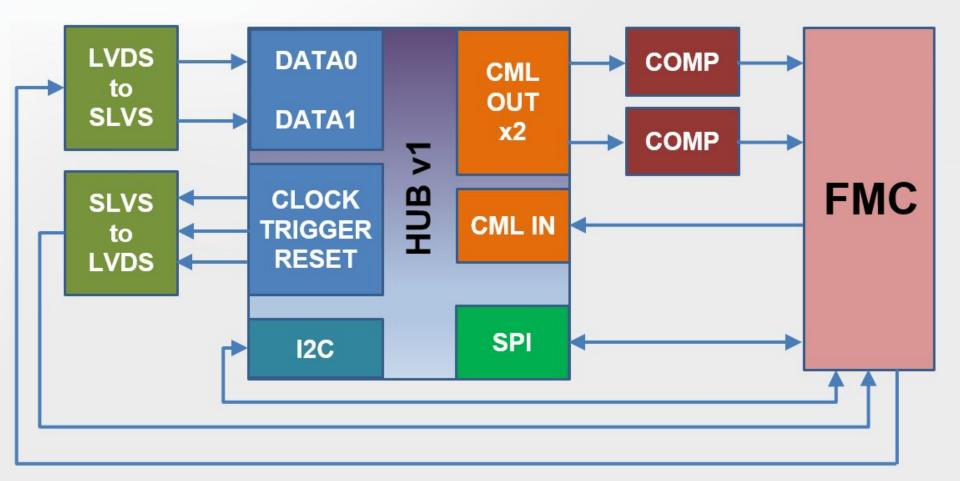


Lab test bench

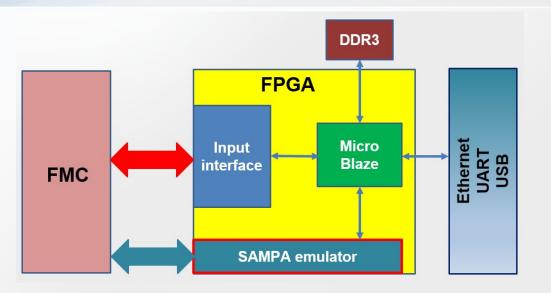
Aim - checking functionality of the chip at lab conditions



Test board block diagram



KC705 FPGA control board





Key features:

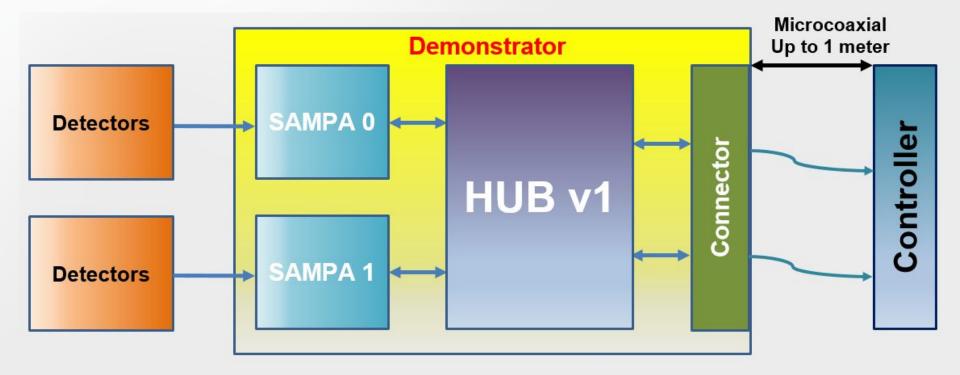
- Kintex-7 XC7K325T FPGA with MicroBlaze capability
- 1 GB DDR3 memory
- USB port with USB-to-UART bridge
- 1000 Mb/s Ethernet interface
- FMC HPC:

4 high-speed GTX transceivers about 70 differential LVDS lines

First lab test bench results for Hub v1 chip

- 1) Functionality has been confirmed for a few building blocks only
- Problems have been verified. Standard digital pads do not (!)
 connected to the internal chip routing
- All tests (incl. ones under irradiation) have been performed with working analog blocks only

The demonstrator concept

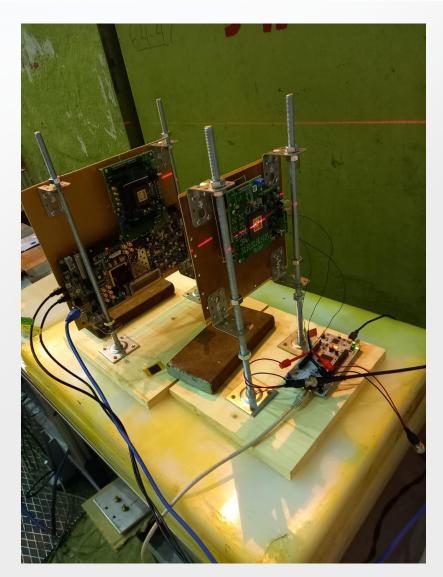


The demonstrator board photo



The lab testbench in calibrated beam

Purpose - checking functionality of the chip blocks against heavy particles. Tests were done at PNPI, Gatchina in Feb. 2022





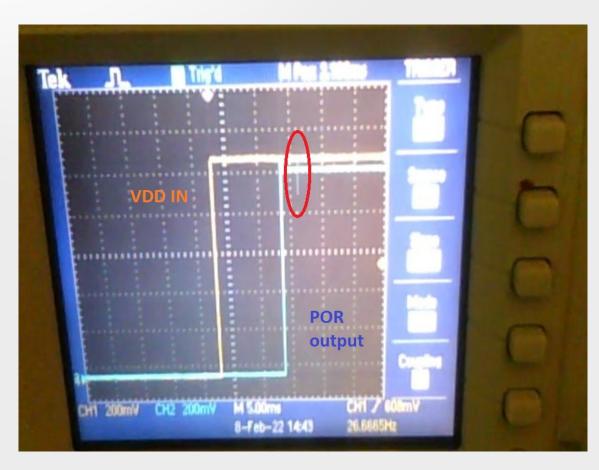
Test radiation environment

- Radiation tests were performed in PNPI at Gatchina according to GOST 15.101-98
- 2) Bunch characteristics:
 - a) particles, energy: protons, 1 GeV
 - b) bunch diameter, uniformity: 19 mm, 5%
 - c) fluence: $5 * 10^7 5 * 10^8$ particles / cm² / s
- 3) Experiment characteristics:
 - a) Irradiation duration: 10 hours
 - b) Average fluence: 2 * 10⁸ particles / cm² / s
 - c) Total fluence: 2.54×10^{12}

First results

2 types of test records:

- analog type (video record from scope to camera)
- digital one (signals, digitized by ADC) now in data processing



Next version of the chip – Hub v2

Destination:

- 1) Shift to a new process 90 nm CMOS of Mikron (Zelenograd).
- Study measures to improve the radiation resistance of the IP blocks against heavy charged particles
- 3) Optimize the size and functionality of the digital blocks
- Study chip caseless usage at board level. The flip-chip technique is not considered at the moment
- The chip should be a socket compatible with the manufactured Demonstrator board (one for Hub v1 chip)

Hub v2 schedule

- Redesign of the Hub v1 from TSMC 65 nm CMOS process to Mikron 90 nm one (readiness of the GDSII-file – Feb. 2023)
- 2) Chip processing at Mikron (late 2023, tens pcs.)
- 3) Lab evaluation board design and manufacturing (late 2023)
- 4) Test results (spring 2024)

Summary

- Since the last MPD meeting two versions of PCBs for study the Hub v1 ASIC were designed and manufactured to develop:
 - Lab test bench to check chip functionality
 - Demonstrator board for TPC
- Elaboration of the specifications for the 2nd chip version has been started. It should be compatible with 90 nm CMOS process of Mikron factory at Zelenograd